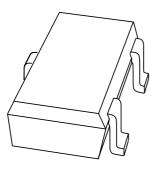
DISCRETE SEMICONDUCTORS

DATA SHEET



BZB784 seriesVoltage regulator double diodes

Product data sheet Supersedes data of 2000 May 24 2001 Feb 27



Voltage regulator double diodes

BZB784 series

FEATURES

• Total power dissipation: max. 350 mW

• Approx. 5% V_Z tolerance

• Working voltage range: nom. 2.4 to 15 V (E24 range).

APPLICATIONS

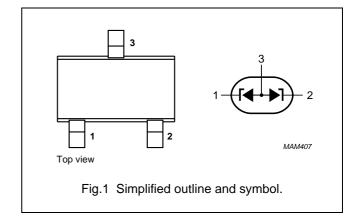
- · General regulation functions
- ESD and surge protection.

DESCRIPTION

Low-power voltage regulator diodes in a small SOT323 (SC-70) package.

PINNING SOT323 (SC-70)

| PIN | DESCRIPTION |
|-----|--------------|
| 1 | cathode |
| 2 | cathode |
| 3 | common anode |



MARKING

| TYPE NUMBER | MARKING CODE | TYPE NUMBER | MARKING CODE | TYPE NUMBER | MARKING CODE | TYPE NUMBER | MARKING CODE |
|----------------|-----------------|----------------|-----------------|----------------|-----------------|----------------|-----------------|
| BZB784-C2V4 | 91 | BZB784-C3V9 | 96 | BZB784-C6V2 | 9B | BZB784-C10 | 9G |
| BZB784-C2V7 | 92 | BZB784-C4V3 | 97 | BZB784-C6V8 | 9C | BZB784-C11 | 9H |
| BZB784-C3V0 | 93 | BZB784-C4V7 | 98 | BZB784-C7V5 | 9D | BZB784-C12 | 9J |
| BZB784-C3V3 | 94 | BZB784-C5V1 | 99 | BZB784-C8V2 | 9E | BZB784-C13 | 9K |
| BZB784-C3V6 | 95 | BZB784-C5V6 | 9A | BZB784-C9V1 | 9F | BZB784-C15 | 9L |

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | MIN. | MAX. | UNIT | |
|------------------|---|---|-----------|------|----|
| I _F | continuous forward current | | _ | 200 | mA |
| I _{ZSM} | non-repetitive peak reverse current | t _p = 100 μs; square wave; T _{amb} = 25 °C; prior to surge | see Table | 1 | |
| P _{tot} | total power dissipation; note 1 | T _{amb} = 25 °C; 2 diodes loaded | _ | 350 | mW |
| | | T _{amb} = 25 °C; 1 diode loaded | _ | 180 | mW |
| P _{ZSM} | non-repetitive peak reverse dissipation | t_p = 100 μs; square wave; T_{amb} = 25 °C; prior to surge | _ | 40 | W |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | _ | 150 | °C |

Note

1. Device mounted on an FR4 printed-circuit board.

Voltage regulator double diodes

BZB784 series

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------------|---|-------------------------|-------|------|
| R _{th j-s} | thermal resistance from junction to soldering point | 2 diodes loaded; note 1 | 140 | K/W |
| | | 1 diode loaded; note 1 | 265 | K/W |
| R _{th j-a} | thermal resistance from junction to ambient | 2 diodes loaded; note 2 | 355 | K/W |
| | | 1 diode loaded; note 2 | 680 | K/W |

Notes

- 1. Solder points on cathode tabs.
- 2. Device mounted on a FR4 printed-circuit board.

ELECTRICAL CHARACTERISTICS

Total BZB784-C series

 $T_j = 25$ °C; unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MAX. | UNIT |
|----------------|-----------------|-----------------------------------|------|------|
| V _F | forward voltage | I _F = 10 mA; see Fig.2 | 0.9 | V |
| I _R | reverse current | | | |
| | BZB784-C2V4 | $V_R = 1 V$ | 50 | μΑ |
| | BZB784-C2V7 | $V_R = 1 V$ | 20 | μΑ |
| | BZB784-C3V0 | $V_R = 1 V$ | 10 | μΑ |
| | BZB784-C3V3 | V _R = 1 V | 5 | μΑ |
| | BZB784-C3V6 | V _R = 1 V | 5 | μΑ |
| | BZB784-C3V9 | V _R = 1 V | 3 | μΑ |
| | BZB784-C4V3 | $V_R = 1 V$ | 3 | μΑ |
| | BZB784-C4V7 | V _R = 2 V | 3 | μΑ |
| | BZB784-C5V1 | V _R = 2 V | 2 | μΑ |
| | BZB784-C5V6 | V _R = 2 V | 1 | μΑ |
| | BZB784-C6V2 | V _R = 4 V | 3 | μΑ |
| | BZB784-C6V8 | V _R = 4 V | 2 | μΑ |
| | BZB784-C7V5 | V _R = 5 V | 1 | μΑ |
| | BZB784-C8V2 | V _R = 5 V | 700 | nA |
| | BZB784-C9V1 | V _R = 6 V | 500 | nA |
| | BZB784-C10 | V _R = 7 V | 200 | nA |
| | BZB784-C11 | V _R = 8 V | 100 | nA |
| | BZB784-C12 | V _R = 8 V | 100 | nA |
| | BZB784-C13 | V _R = 8 V | 100 | nA |
| | BZB784-C15 | V _R = 10.5V | 50 | nA |

Voltage regulator double diodes

Product data sheet

Table 1Per type BZB784-C2V4 to C15

T_j = 25 °C; unless otherwise specified.

| BZB784-C XXX | VOLT V _Z | WORKING VOLTAGE V_Z (V) at $I_Z = 5$ mA | | | _ RESISTANCE (Ω) | | TEMP. COEFFICIENT S _Z (mV/K) at I _{Ztest} = 5 mA | DIODE CAP. C_d (pF) at f = 1 MHz; $V_R = 0 V$ | NON-REPETITIVE PEAK REVERSE CURRENT I _{ZSM} (A) at t _p = 100 μs; |
|-----------------|------------------------|---|---------------------|--------|---------------------|--------|--|--|--|
| 7001 | Tol. | ≈5% | at I _Z = | : 1 mA | at I _Z = | = 5 mA | (see Figs 3 and 4) | V _R = U V | T _{amb} = 25 °C |
| | MIN. | MAX. | TYP. | MAX. | TYP. | MAX. | TYP. | MAX. | MAX. |
| 2V4 | 2.2 | 2.6 | 275 | 600 | 70 | 100 | -1.3 | 450 | 6.0 |
| 2V7 | 2.5 | 2.9 | 300 | 600 | 75 | 100 | -1.4 | 450 | 6.0 |
| 3V0 | 2.8 | 3.2 | 325 | 600 | 80 | 95 | -1.6 | 450 | 6.0 |
| 3V3 | 3.1 | 3.5 | 350 | 600 | 85 | 95 | -1.8 | 450 | 6.0 |
| 3V6 | 3.4 | 3.8 | 375 | 600 | 85 | 90 | -1.9 | 450 | 6.0 |
| 3V9 | 3.7 | 4.1 | 400 | 600 | 85 | 90 | -1.9 | 450 | 6.0 |
| 4V3 | 4.0 | 4.6 | 410 | 600 | 80 | 90 | -1.7 | 450 | 6.0 |
| 4V7 | 4.4 | 5.0 | 425 | 500 | 50 | 80 | -1.2 | 300 | 6.0 |
| 5V1 | 4.8 | 5.4 | 400 | 480 | 40 | 60 | -0.5 | 300 | 6.0 |
| 5V6 | 5.2 | 6.0 | 80 | 400 | 15 | 40 | 1.0 | 300 | 6.0 |
| 6V2 | 5.8 | 6.6 | 40 | 150 | 6 | 10 | 2.2 | 200 | 6.0 |
| 6V8 | 6.4 | 7.2 | 30 | 80 | 6 | 15 | 3.0 | 200 | 6.0 |
| 7V5 | 7.0 | 7.9 | 30 | 80 | 6 | 15 | 3.6 | 150 | 4.0 |
| 8V2 | 7.7 | 8.7 | 40 | 80 | 6 | 15 | 4.3 | 150 | 4.0 |
| 9V1 | 8.5 | 9.6 | 40 | 100 | 6 | 15 | 5.2 | 150 | 3.0 |
| 10 | 9.4 | 10.6 | 50 | 150 | 8 | 20 | 6.0 | 90 | 3.0 |
| 11 | 10.4 | 11.6 | 50 | 150 | 10 | 20 | 6.9 | 90 | 2.5 |
| 12 | 11.4 | 12.7 | 50 | 150 | 10 | 25 | 7.9 | 85 | 2.5 |
| 13 | 12.4 | 14.1 | 50 | 170 | 10 | 30 | 8.8 | 80 | 2.5 |
| 15 | 13.8 | 15.6 | 50 | 200 | 10 | 30 | 10.7 | 75 | 2.0 |

Voltage regulator double diodes

BZB784 series

GRAPHICAL DATA

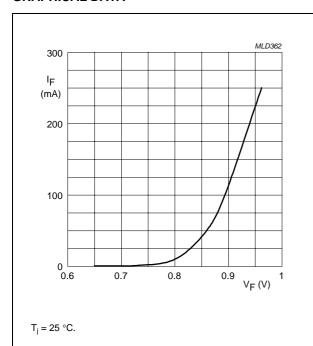
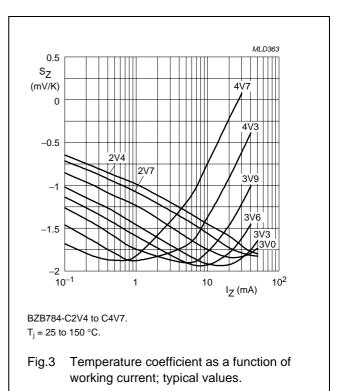
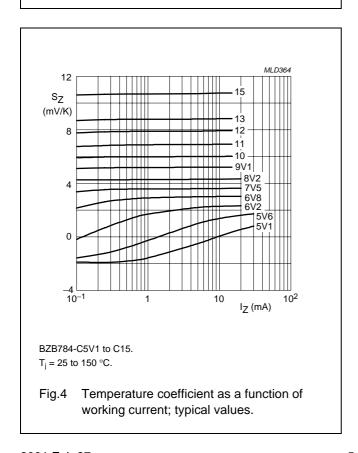


Fig.2 Forward current as a function of forward voltage; typical values.





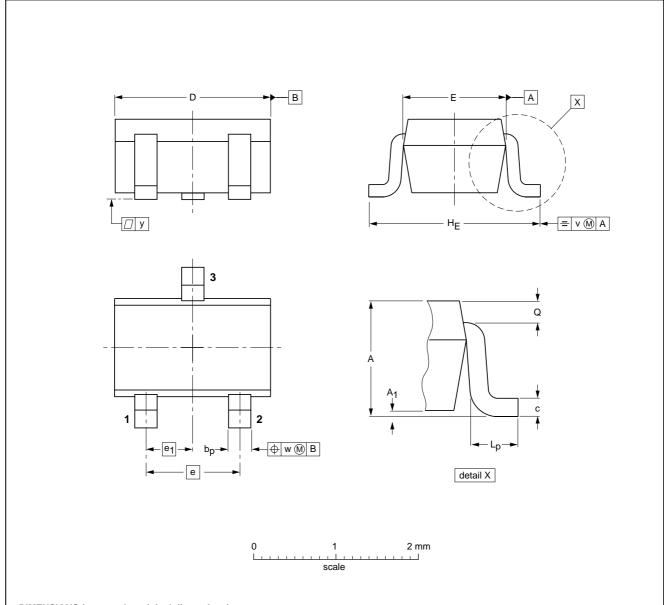
Voltage regulator double diodes

BZB784 series

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT323



DIMENSIONS (mm are the original dimensions)

| UNIT | Α | A ₁ max | bp | С | D | E | е | e ₁ | HE | Lp | Q | v | w |
|------|------------|-----------------------|------------|--------------|------------|--------------|-----|----------------|------------|--------------|--------------|-----|-----|
| mm | 1.1 0.8 | 0.1 | 0.4 0.3 | 0.25 0.10 | 2.2 1.8 | 1.35 1.15 | 1.3 | 0.65 | 2.2 2.0 | 0.45 0.15 | 0.23 0.13 | 0.2 | 0.2 |

| OUTLINE | | REFER | EUROPEAN | ISSUE DATE | |
|---------|-----|-------|----------|------------|------------|
| VERSION | IEC | JEDEC | EIAJ | PROJECTION | ISSUE DATE |
| SOT323 | | | SC-70 | | 97-02-28 |

Voltage regulator double diodes

BZB784 series

DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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